



**CHENMKO ENTERPRISE CO.,LTD**

*Lead free devices*

**SURFACE MOUNT**  
SCHOTTKY BARRIER DIODE  
VOLTAGE 30 Volts CURRENT 0.1 Ampere

**CH548TSPT**

**APPLICATION**

- \* General purpose detection
- \* High speed switching

**FEATURE**

- \* Small surface mounting dual element linear type.  
(SC-75/SOT-416)
- \* Low VF and low IR.
- \* High reliability

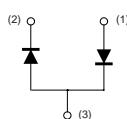
**CONSTRUCTION**

- \* Silicon epitaxial planar

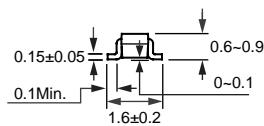
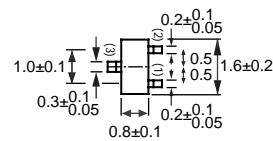
**MARKING**

- \* 3N

**CIRCUIT**



**SC-75/SOT-416**



Dimensions in millimeters

**SC-75/SOT-416**

**MAXIMUM RATINGS ( At TA = 25°C unless otherwise noted )**

RATINGS	SYMBOL	CH548TSPT	UNITS
Maximum Recurrent Peak Reverse Voltage	V <sub>RRM</sub>	30	Volts
Maximum RMS Voltage	V <sub>RMS</sub>	21	Volts
Maximum DC Blocking Voltage	V <sub>Dc</sub>	30	Volts
Maximum Average Forward Rectified Current	I <sub>O</sub>	0.1	Amps
Peak Forward Surge Current at 8.3 mSec single half sine-wave	I <sub>FSM</sub>	0.5	Amps
Typical Junction Capacitance between Terminal (Note 1)	C <sub>J</sub>	4.0	pF
Maximum Operating Temperature Range	T <sub>J</sub>	+125	°C
Storage Temperature Range	T <sub>STG</sub>	-40 to +125	°C

**ELECTRICAL CHARACTERISTICS ( At TA = 25°C unless otherwise noted )**

CHARACTERISTICS	SYMBOL	CH548TSPT	UNITS
Maximum Instantaneous Forward Voltage at I <sub>F</sub> = 10mA	V <sub>F</sub>	0.45	Volts
Maximum Average Reverse Current at V <sub>R</sub> = 10V	I <sub>R</sub>	0.5	uAmps

NOTES : 1. Measured at 1.0 MHz and applied reverse voltage of 10.0 volts.  
2. ESD sensitive product handling required.

2003-5

## RATING CHARACTERISTIC CURVES ( CH548TSPT )

FIG. 1 - FORWARD CHARACTERISTICS

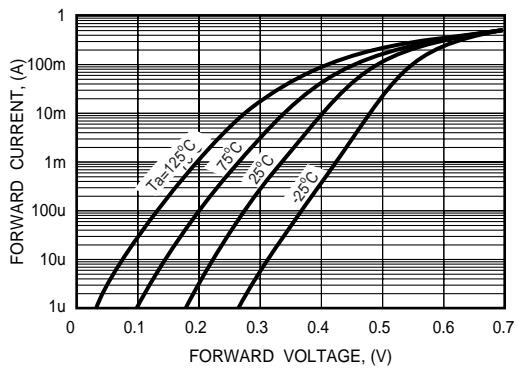


FIG. 2 - REVERSE CHARACTERISTICS

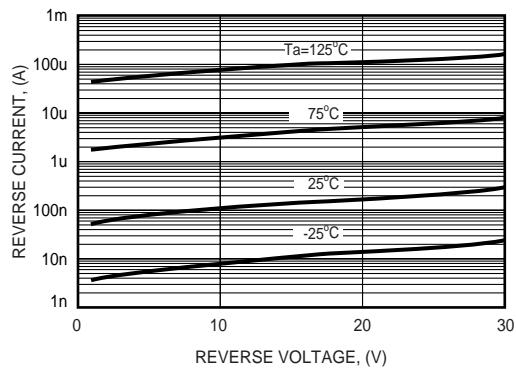


FIG. 3 - TYPICAL JUNCTION CAPACITANCE

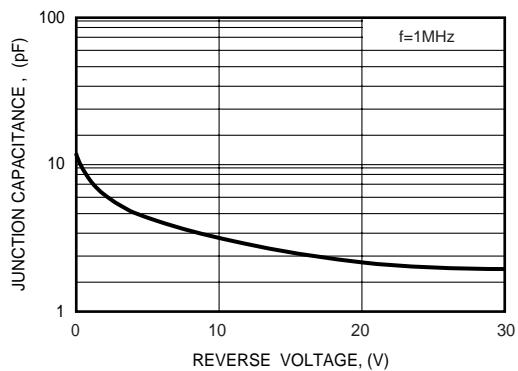


FIG. 4 - TYPICAL FORWARD CURRENT DERATING CURVE

